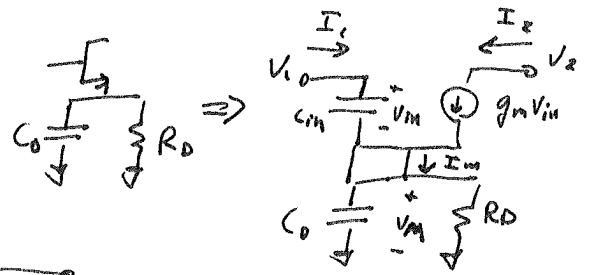


① Show that emitter degeneration



is equivalent to: $\frac{1}{s} C_{in} \parallel g_m V_{in}$ $C_{in} = C_{in} / (1 + g_m R_D)$
 $\tilde{g}_m = g_m / (1 + g_m R_D)$

when $C_D R_D = C_{in} / g_m$. Find Y parameters.

• $Y_{11} = \frac{I_1}{V_1} |_{V_2=0}$

• $V_1 = V_{in} + V_M$

• $I_1 = V_{in} j\omega C_{in}$

Given $C_D R_D = C_{in} / g_m$

$$\left. \begin{aligned} I_M &= V_{in} (j\omega C_{in} + g_m) \\ V_M &= I_M \cdot \frac{1}{j\omega C_D + 1/R_D} \end{aligned} \right\} V_M = V_{in} \cdot \frac{j\omega C_{in} + g_m}{j\omega C_D + 1/R_D} = V_{in} R_D \cdot \frac{j\omega C_{in} + g_m}{j\omega C_{in} / g_m + 1}$$

$$= V_{in} R_D g_m \cdot \frac{j\omega C_{in} + g_m}{j\omega C_{in} + g_m} = V_{in} R_D g_m$$

so, $V_1 = V_{in} + V_M = V_{in} (1 + g_m R_D)$

$$Y_{11} = \frac{V_{in} j\omega C_{in}}{V_{in} (1 + g_m R_D)} = \frac{j\omega C_{in}}{1 + g_m R_D} = j\omega \tilde{C}_{in} = Y_{11}$$

• $Y_{12} = \frac{I_1}{V_2} |_{V_1=0} = 0$ since $C_{D0} = 0$

• $Y_{22} = \frac{I_2}{V_2} |_{V_1=0} = 0$ since I_2 depends on V_{in} only

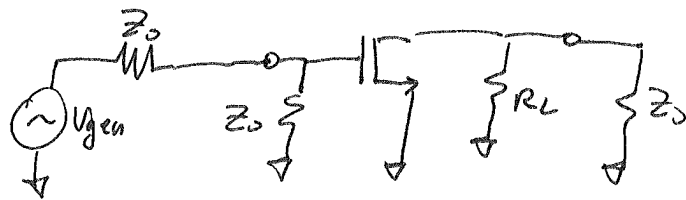
• $Y_{21} = \frac{I_2}{V_1} |_{V_2=0}$

$I_2 = g_m V_{in}$

$V_1 = V_{in} + V_M = V_{in} (1 + g_m R_D)$

$$Y_{21} = \frac{g_m}{1 + g_m R_D} = \tilde{g}_m$$

(2)



$$g_m = 1 \frac{\text{mS}}{\mu\text{m}} \cdot W_g \Rightarrow W_g = \frac{g_m}{1 \text{ mS}/\mu\text{m}}$$

$$R_i = 0.5/g_m$$

$$g_m R_{os} = 20 \Rightarrow R_{os} = 20/g_m$$

$$C_{gd} = 0$$

$$f_T = 200 \text{ GHz} \rightarrow f_T \approx \frac{g_m}{2\pi C_{gs}}$$

$$S_{21} = 10 \text{ dB}$$

* Find R_L, W_g, f_{3dB}

$$S_{21} = 20 \log |A_V|$$

$$A_V = 10^{S_{21}/20} = 3.16$$

From baseband analysis $A_V = g_m R_{L,eq}$ where $R_{L,eq} = R_{os} \parallel R_L \parallel Z_0$

We must also match $R_{os} \parallel R_L$ to 50Ω to minimize Reflections

$$\text{Thus: } 50 = \left(\frac{1}{R_{os}} + \frac{1}{R_L} \right) = \left(\frac{g_m}{20} + \frac{1}{R_L} \right)$$

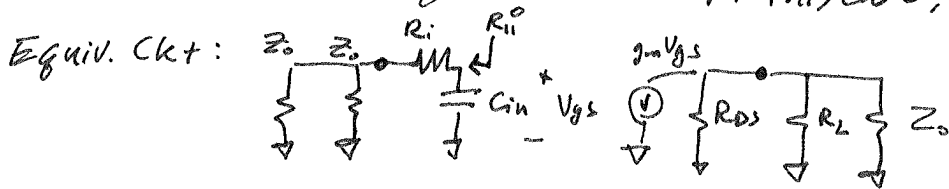
$$3.16 = g_m \left(\frac{1}{R_{os}} + \frac{1}{R_L} + \frac{1}{Z_0} \right) = g_m \left(\frac{g_m}{20} + \frac{1}{R_L} + \frac{1}{50} \right)$$

Solve by hand or computer:

$$g_m = 0.1265 \Rightarrow W_g = 126.5 \mu\text{m}$$

$$R_L = 73.12 \Omega$$

f_{3dB} is determined by dominant, or in this case, the only pole: a_1



$$R_i = 0.5/g_m = 3.9$$

$$C_{in} = \frac{g_m}{2\pi f_T} = 100 \text{ fF}$$

Using MOTC with respect to C_{in} : $R_{ii}^o = R_i + Z_0/2 = 28.9$

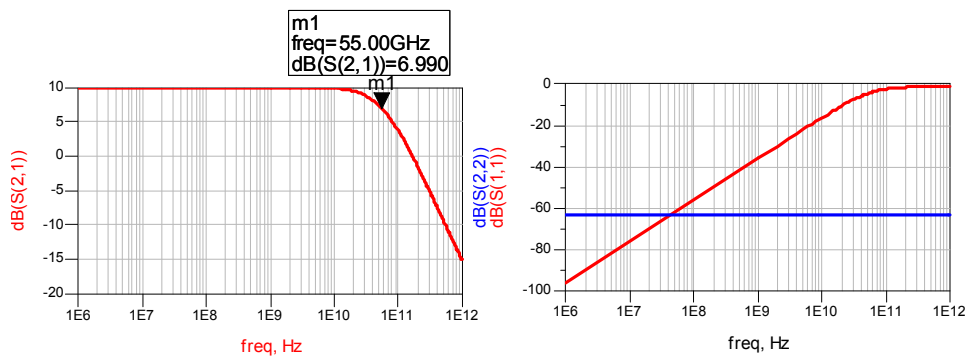
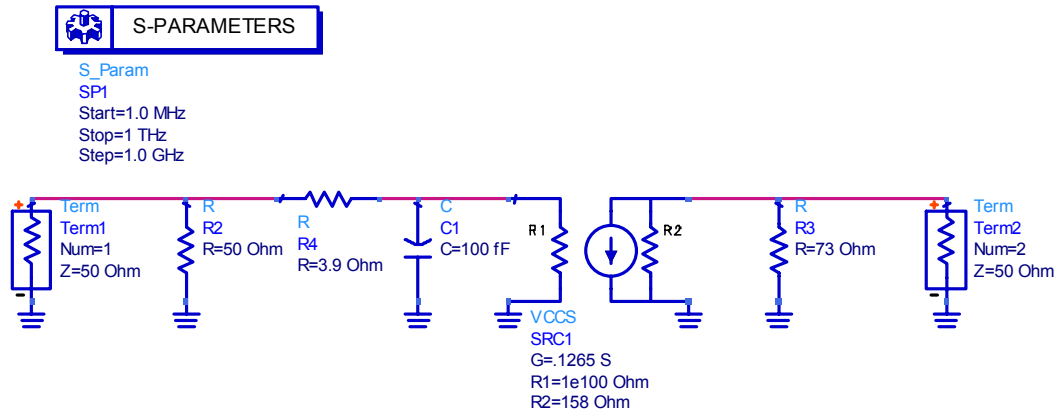
$$a_1 = R_{ii}^o C_{in} = 2.89 \text{ ps}$$

$$f_{3dB} = \frac{1}{2\pi(2.89 \text{ ps})} = 55.1 \text{ GHz}$$

For this simple case with 1 capacitor the pole is exactly where we expect: $f_p = \frac{1}{2\pi RC}$
MOTC will be helpful in more complex circuits.

Problem #2

Derived parameters entered in schematic:

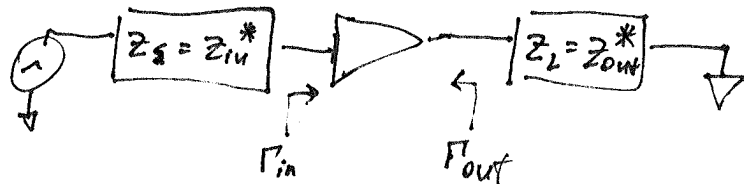


Results: The spec of 10dB low frequency gain is met, with f_{3dB} at 55GHz as predicted by analysis.

Input and output are well matched at low frequencies by the resistive termination. However, S_{11} increases at 20dB/dec because of the input capacitor.

③ For Problem 2's transistor find
 Max available power gain (MAG) @ 50 GHz
 and f_{max} (where $MAG = 1$)

For MAG, input & output are both conjugate matched,
 so Γ_{in} and $\Gamma_{out} = 0$



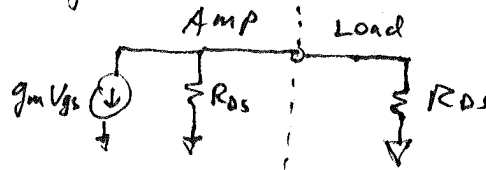
$$\begin{aligned} C_{gs} &= 100 \text{ fF} \\ C_{gd} &= 0 \\ R_{in} &= 3.9 \text{ } \Omega \\ R_{ds} &= 158 \text{ } \Omega \\ g_m &= 0.1265 \end{aligned}$$

$$P_{in} = I_{in}^2 R_{in}, \quad V_{gs} = I_{in} \omega C_{gs}$$

$$P_{out} = I_{out}^2 R_{out} \quad \text{For matching output we need } Z_L = R_{ds}$$

$$\text{so } I_{out} = g_m V_{gs} / 2$$

$$P_{out} = \left(\frac{g_m V_{gs}}{2} \right)^2 R_{ds}$$



$$MAG = \frac{P_{out}}{P_{in}} = \frac{g_m^2 R_{ds}}{4 \omega^2 C_{gs}^2 R_{in}}$$

$$MAG(50 \text{ GHz}) = \frac{(0.1265)^2 \cdot 158}{4 \times (2\pi \times 50 \times 10^9)^2 \cdot (100 \times 10^{-15})^2 \cdot 3.9} = 164.2$$

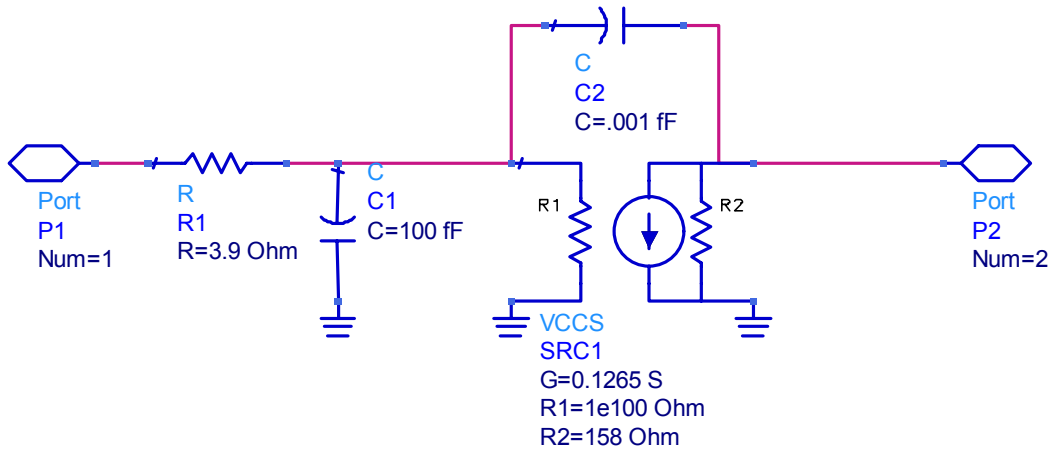
$$10 \cdot \log 164.2 = 22 \text{ dB} = MAG(50 \text{ GHz})$$

→ ADS gives 22 dB

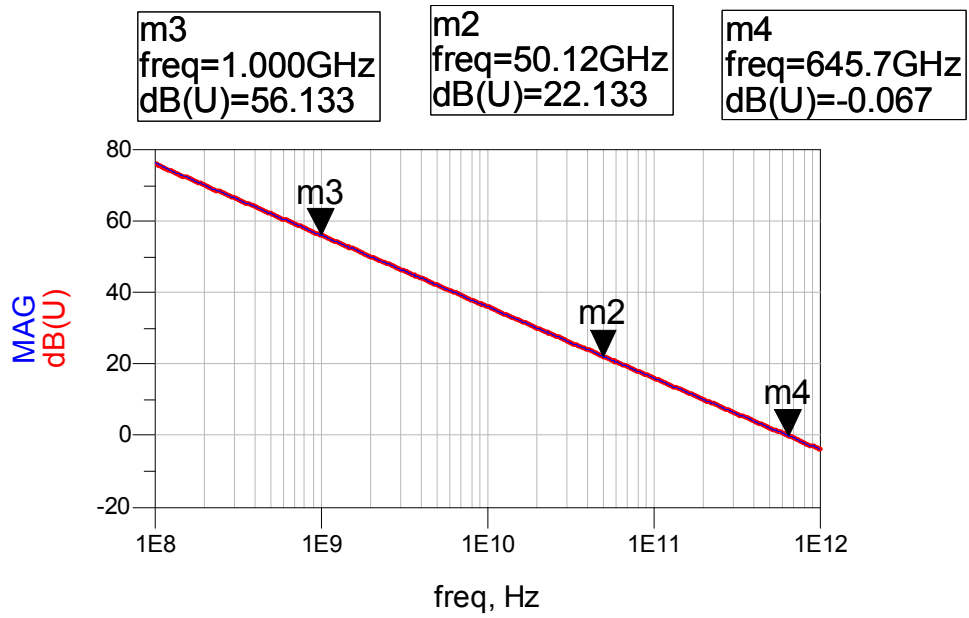
$$\text{a) } f_{max} \text{ } MAG \equiv 1 = \frac{g_m^2 R_{ds}}{4 \omega_{max}^2 C_{gs}^2 R_{in}}$$

$$\Rightarrow f_{max} = \frac{g_m}{4\pi C_{gs}} \sqrt{\frac{R_{ds}}{R_{in}}} = 641 \text{ GHz} = f_{max}$$

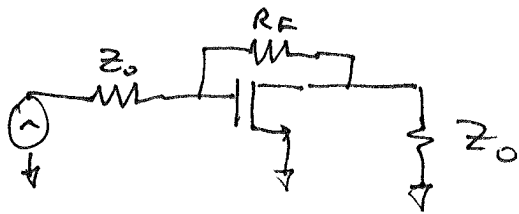
→ ADS gives ~645 GHz



Tested with the Gain-testbench file which Prof. Rodwell provides on course website.



(4)



Feedback amp w/ same FET parameters as problem 2.

Let $R_i = R_{DS} = 0$ to simplify.

Given: $S_{21} = 10 \text{ dB}$
 $\Rightarrow A_V = 3.16$

To match to 50Ω so $S_{11} = 0$ @ low freq. :

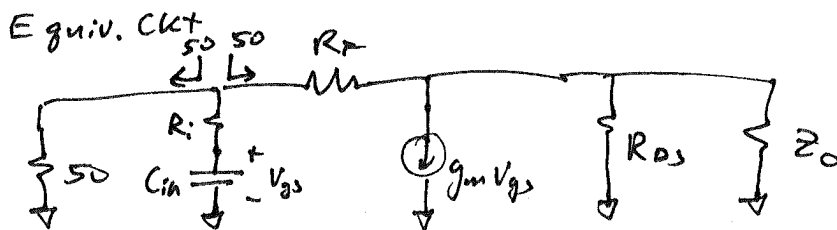
$$\rightarrow R_F = Z_0 (1 + A_V) = 208 \Omega$$

$$\rightarrow g_m = (1 + A_V) / Z_0 = 0.0833 \text{ S}$$

$$\rightarrow W_g = g_m / I_{DS} / \mu\text{m} = 83 \mu\text{m}$$

$$\rightarrow C_{in} \approx g_m / 2\pi f_T = 66 \text{ fF}$$

3dB BW



$$R_i = \frac{0.5}{g_m} = 6 \Omega$$

By definition of our analysis, if we neglect R_i :
 then R_{ii}^0 for $C_{in} = 50 // 50 = 25$

$$\text{so } f_{3dB} = \frac{1}{2\pi(25)(66 \text{ fF})} = \approx 96.5 \text{ GHz}$$

this is a little high because R_i was neglected,
 so add it back in : $R_{ii}^0 = 6 + 50 // 50 = 31$

$$f_{3dB} = \frac{1}{2\pi(31)(66 \text{ fF})} = 77.5 \text{ GHz}$$

A much better match with simulation

Problem #4



S-PARAMETERS

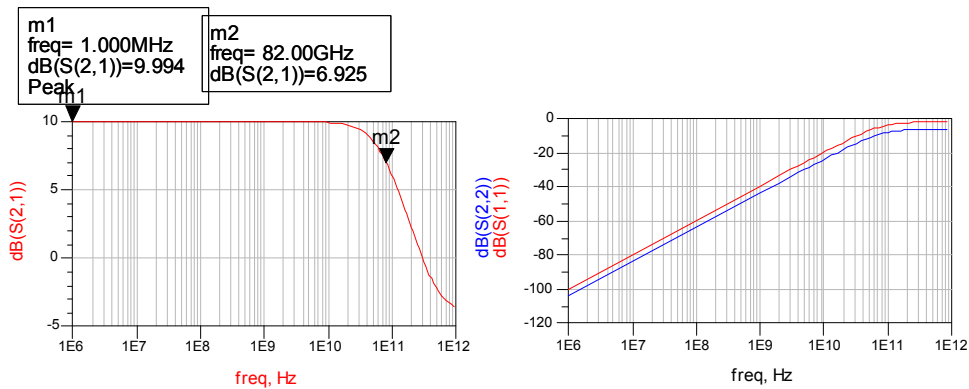
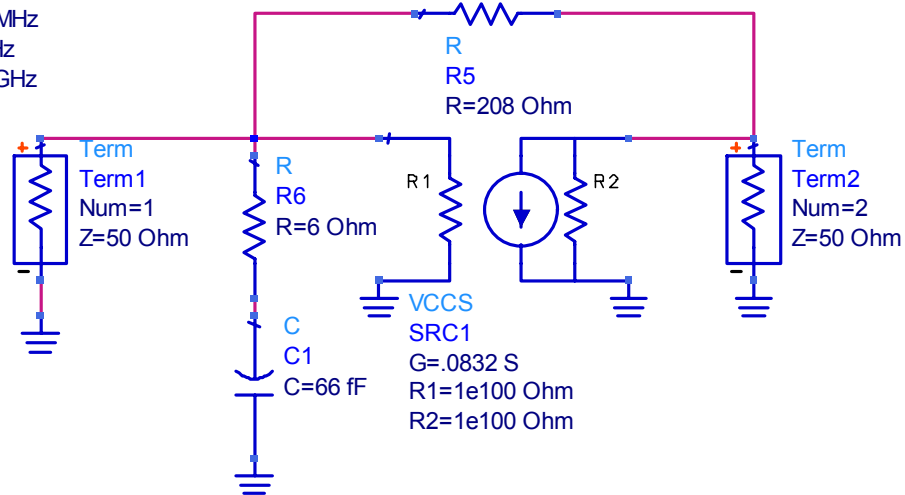
S_Param

SP1

Start=1.0 MHz

Stop=1 THz

Step=1.0 GHz



We observe that the low frequency gain is 10dB as we designed it for. The match is quite good at low frequencies, the input and output reflections both increase at 20dB/dec.

The f_{3dB} is about 82 GHz, a decent match with our calculations.